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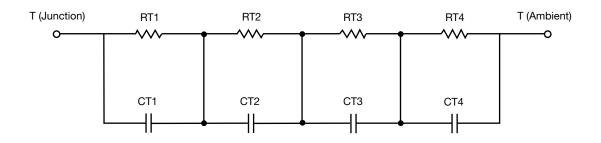
R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

R-C THERMAL MODEL FOR TANK CONFIGURATION



-C VALUES FOR TANK CONFIGURATION						
THERMAL RESISTANCE (°C/W)						
Junction to	Ambient	Case	Foot			
RT1	6.8691	N/A	6.9691			
RT2	29.7186	N/A	7.1401			
RT3	22.2929	N/A	16.5264			
RT4	51.1194	N/A	7.4970			
	THERMAL CAPACI	TANCE (Joules/°C)	÷			
Junction to	Ambient	Case	Foot			
CT1	192.4257u	N/A	24.4542m			
CT2	2.8877m	N/A	97.5800u			
CT3	61.5344m	N/A	1.1742m			
CT4	1.7756	N/A	8.7921m			

Note

N/A indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

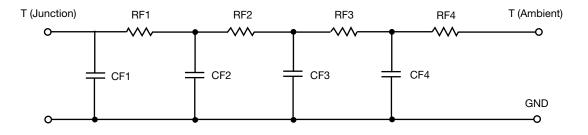
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R-C THERMAL MODEL FOR FILTER CONFIGURATION



THERMAL RESISTANCE (°C/W)						
Junction to	Ambient	Case	Foot			
RF1	13.5537	N/A	9.0737			
RF2	34.6494	N/A	20.2614			
RF3	31.5664	N/A	4.4365			
RF4	30.2305	N/A	4.2630			
	THERMAL CAPACIT	TANCE (Joules/°C)	·			
Junction to	Ambient	Case	Foot			
CF1	368.1080u	N/A	94.6325u			
CF2	4.7639m	N/A	1.0386m			
CF3	503.7330m	N/A	4.3147m			
CF4	3.5416	N/A	28.7568m			

Note

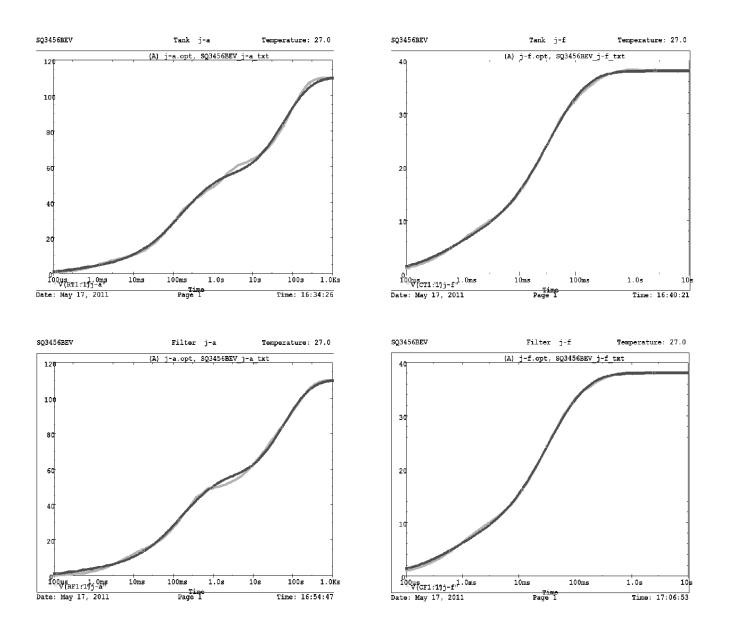
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